



**A flip-chip bonder for high-speed, high-quality placement of bare ICs for cutting-edge devices**

## MD-P300 Flip-chip Bonder

The MD-P300 Flip-chip Bonder is process-flexible, combining flip-chip and thermosonic bonding in a single, small-footprint solution. The MD-P300 contributes to the cost-effective production (high yield, high throughput) of value-added devices. The MD-P300 can achieve high speed and high accuracy bonding through its low gravity point and lightweight bonding head. The MD-P300 supports 300 mm (12") wafers, and is an ideal solution for COB hybrid assembly in combination with an in-line Panasonic SMT placement machine. The MD-P300 is capable of fast cycle times and a placement accuracy of  $\pm 5 \mu\text{m}$  at 0.5 seconds per IC (dry run) - with thermosonic processes at 0.65 seconds, including process times.

### Key Features

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The basic structure comprises fixed-point pickup and placement that supports supply of wafers up to  $\varnothing 300 \text{ mm}$

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Process change is possible by switching the bonding tool (Compatible with GGI/C4/TCB)

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High-precision placement of  $\pm 5 \mu\text{m}$  is achieved using the placement nozzle where the chip backside recognition result obtained by a flip camera is feed-forwarded to handling

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For productivity, high-speed placement of 5,500 CPH (production output per hour) is achieved

MD-P300 Flip-chip  
Bonder

<https://ap.connect.panasonic.com/id/en/md-p300-flip-chip-bonder>

<b>Model Number</b>	NM-EFF1 C
<b>Placement Accuracy</b>	XY ( 3σ at Panasonic conditions ) : ±5 μm*1
<b>Substrate dimensions</b>	L 50 mm × W 50 mm to L 330 mm × W 330 mm ( Heating specifications : L 330 mm × W 220 mm )
<b>Die dimensions (mm)</b>	L 1 mm × W 1 mm to L 25 mm × W 25 mm ( Thermosonic : L 7 mm × W 7 mm )
<b>Die Supply</b>	Wafer frame 12 inches ( Option : 8 inches )
<b>Bonding Load</b>	VCM head : 1 N to 50 N ( Option : 2 N to 100 N )
<b>Head Heating</b>	Thermosonic : Up to 300 °C
<b>Substrate Heating</b>	Constant heating , Up to 200 °C ( Heating bonding stage specifications : Max.substrate size L 330 mm × W 220 mm )*2
<b>Power Source</b>	3-phase AC 200 V ±10 V , 50 / 60 Hz , Up to 4 kVA ( Up to 7 kVA for heating specification )*3
<b>Pneumatic Source</b>	0.4 Mpa , 50 L / min ( A.N.R. )( Up to 150 L / min for full-featured machine including cooling air )
<b>Dimensions (mm)</b>	W 1 380 mm × D 1 640 mm × H 1 430 mm ( without loader / unloader )
<b>Footnote Description</b>	Please refer to the specifications on details. <ol style="list-style-type: none"> <li>1. The described productivity and placement accuracy may differ depending on the conditions of use.</li> <li>2. Maximum setting temperature differs depending on the maximum substrate size. Please contact us individually.</li> <li>3. 3-phase 208 / 220 / 380 / 400 / 415 / 480</li> </ol>